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74LVC573A-Q100

Octal D-type transparent latch with 5 V tolerant inputs/outputs; 3-state

1. General description

The 74LVC573A-Q100 consists of eight D-type transparent latches, featuring separate D-type inputs for each latch and 3-state true outputs for bus-oriented applications. A Latch Enable (LE) input and an Output Enable ($\overline{OE}$) input are common to all internal latches.

When LE is HIGH, data at the Dn inputs enters the latches. In this condition, the latches are transparent, that is, a latch output changes each time its corresponding D-input changes. When LE is LOW, the latches store the information that was present at the D-inputs one set-up time preceding the HIGH-to-LOW transition of LE.

When $\overline{OE}$ is LOW, the contents of the eight latches are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance OFF-state. Operation of the $\overline{OE}$ input does not affect the state of the latches.

Inputs can be driven from either 3.3 V or 5 V devices. When disabled, up to 5.5 V can be applied to the outputs. These features allow the use of these devices as translators in mixed 3.3 V or 5 V applications.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from −40 °C to +85 °C and from −40 °C to +125 °C
- 5 V tolerant inputs/outputs, for interfacing with 5 V logic
- Supply voltage range from 1.2 V to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- High-impedance when V_{CC} = 0 V
- Flow-through pinout architecture
- Complies with JEDEC standard:
  - JESD8-7A (1.65 V to 1.95 V)
  - JESD8-5A (2.3 V to 2.7 V)
  - JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

3. Ordering information

Table 1.   **Ordering information**

Type number	Package			Version
	Temperature range	Name	Description	
74LVC573AD-Q100	−40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1
74LVC573APW-Q100	−40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
74LVC573ABQ-Q100	−40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

4. Functional diagram
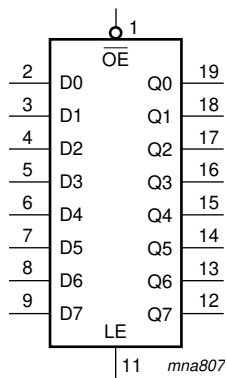
Fig 1.   **Logic symbol**
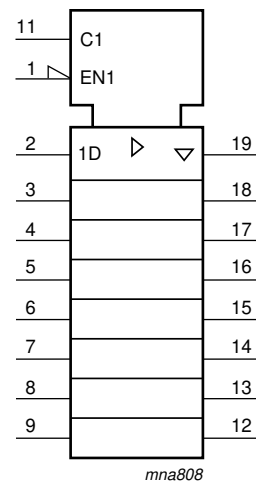
Fig 2.   **IEC logic symbol**
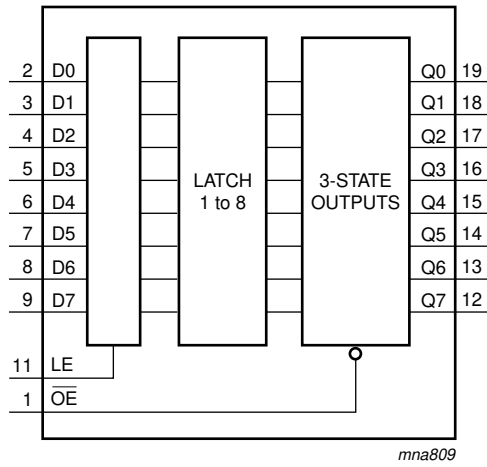
Fig 3.   Functional diagram

Fig 4.   Logic diagram

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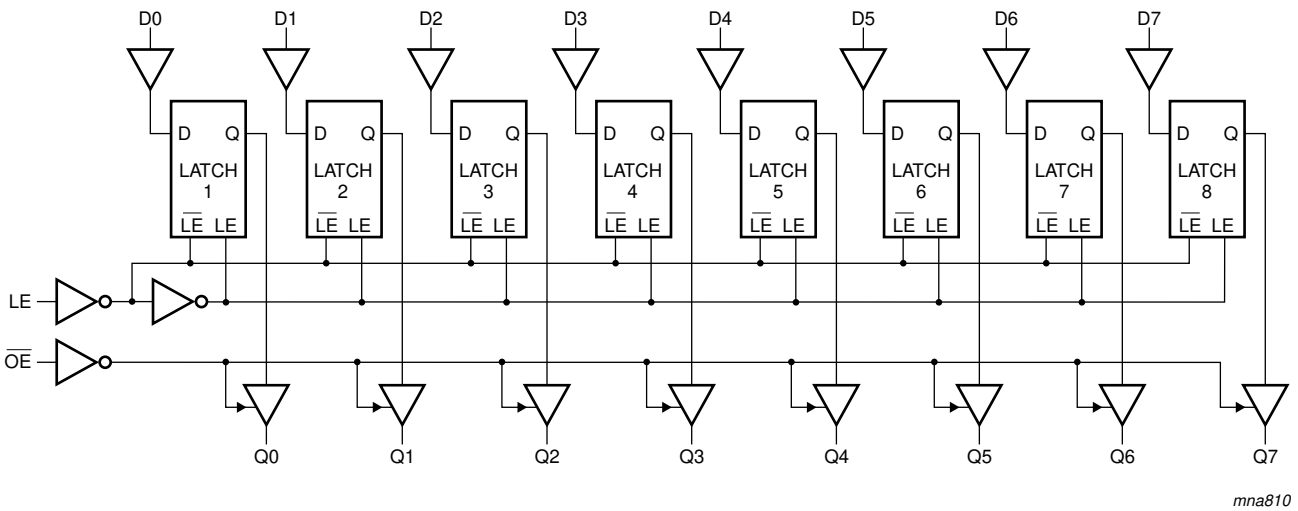
5. Pinning information

5.1 Pinning

Fig 5.   Pin configuration for SO14 and TSSOP14

(1)   This is not a supply pin. The substrate is attached to this pad using conductive die attach material. There is no electrical or mechanical requirement to solder this pad. However, if it is soldered, the solder land should remain floating or be connected to GND.

Fig 6.   Pin configuration for DHVQFN14
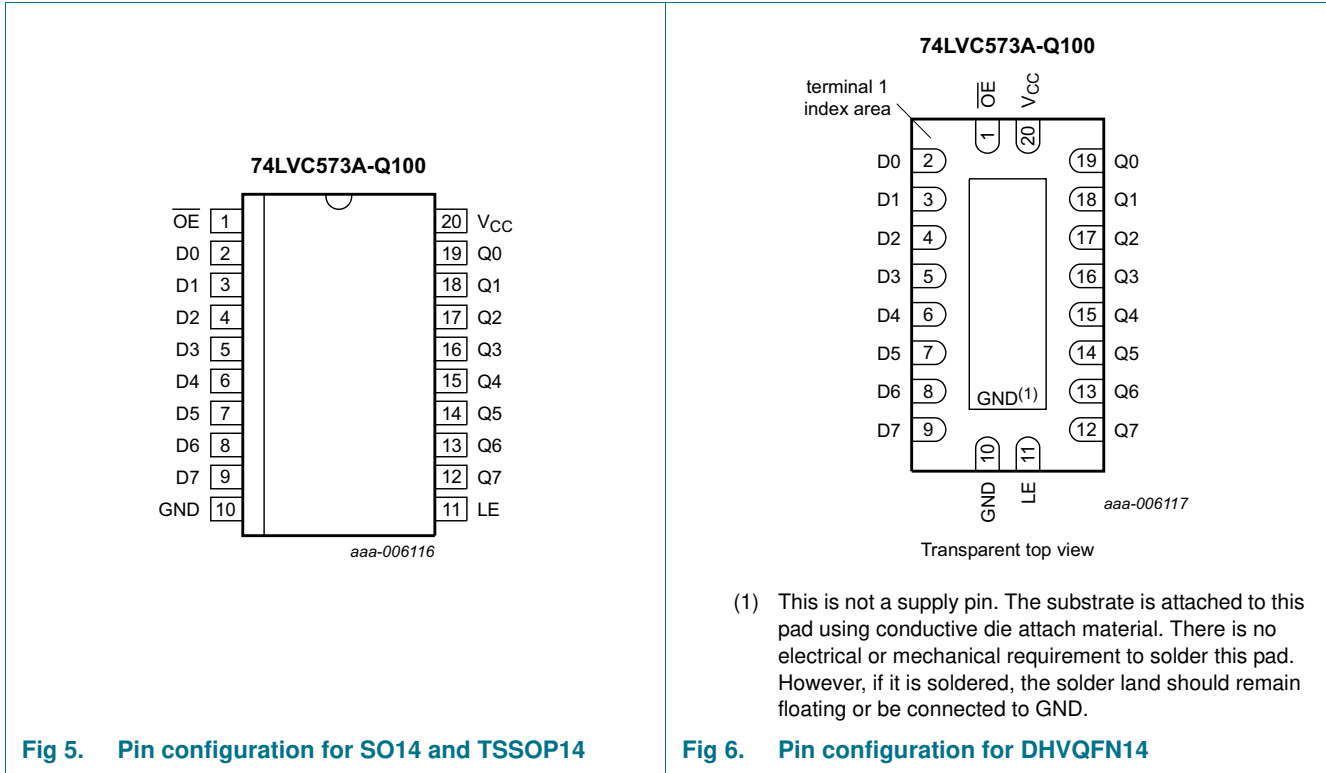
5.2 Pin description

Table 2.   Pin description

Symbol	Pin	Description
$\overline{OE}$	1	output enable input (active LOW)
LE	11	latch enable input (active HIGH)
D[0:7]	2, 3, 4, 5, 6, 7, 8, 9	data input
Q[0:7]	19, 18, 17, 16, 15, 14, 13, 12	data output
GND	10	ground (0 V)
V_{CC}	20	supply voltage

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6. Functional description

Table 3.   Functional table[1]

Operating modes	Input			Internal latch	Output
	$\overline{OE}$	LE	Dn		Qn
Enable and read register (transparent mode)	L	H	L	L	L
	L	H	H	H	H
Latch and read register	L	L	l	L	L
	L	L	h	H	H
Latch register and disable outputs	H	L	l	L	Z
	H	L	h	H	Z

[1]   H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition

L = LOW voltage level

l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition

Z = high-impedance OFF-state

7. Limiting values

Table 4.   Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			−0.5	+6.5	V
I_{IK}	input clamping current	$V_I < 0$		−50	-	mA
V_I	input voltage		[1] −0.5		+6.5	V
I_{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$		-	±50	mA
V_O	output voltage		[2] −0.5		V_{CC} + 0.5	V
I_O	output current	$V_O = 0$ V to V_{CC}		-	±50	mA
I_{CC}	supply current			-	100	mA
I_{GND}	ground current			−100	-	mA
T_{stg}	storage temperature			−65	+150	°C
P_{tot}	total power dissipation	T_{amb} = −40 °C to +125 °C	[3]	-	500	mW

[1]   The minimum input voltage ratings may be exceeded if the input current ratings are observed.

[2]   The output voltage ratings may be exceeded if the output current ratings are observed.

[3]   For SO20 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.

For TSSOP20 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

For DHVQFN20 packages: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

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8. Recommended operating conditions

Table 5. **Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
V_I	input voltage		0	-	5.5	V
V_O	output voltage	output HIGH- or LOW-state	0	-	V_{CC}	V
		output 3-state	0	-	5.5	V
T_{amb}	ambient temperature	in free air	−40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	0	-	20	ns/V
		V_{CC} = 2.7 V to 3.6 V	0	-	10	ns/V

9. Static characteristics

Table 6. **Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	−40 °C to +85 °C			−40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
V_{IH}	HIGH-level input voltage	V_{CC} = 1.2 V	1.08	-	-	1.08	-	V
		V_{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$	-	-	$0.65 \times V_{CC}$	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 1.2 V	-	-	0.12	-	0.12	V
		V_{CC} = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		I_O = −100 μA; V_{CC} = 1.65 V to 3.6 V	$V_{CC} - 0.2$	-	-	$V_{CC} - 0.3$	-	V
		I_O = −4 mA; V_{CC} = 1.65 V	1.2	-	-	1.05	-	V
		I_O = −8 mA; V_{CC} = 2.3 V	1.8	-	-	1.65	-	V
		I_O = −12 mA; V_{CC} = 2.7 V	2.2	-	-	2.05	-	V
		I_O = −18 mA; V_{CC} = 3.0 V	2.4	-	-	2.25	-	V
		I_O = −24 mA; V_{CC} = 3.0 V	2.2	-	-	2.0	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		I_O = 100 μA; V_{CC} = 1.65 V to 3.6 V	-	-	0.2	-	0.3	V
		I_O = 4 mA; V_{CC} = 1.65 V	-	-	0.45	-	0.65	V
		I_O = 8 mA; V_{CC} = 2.3 V	-	-	0.6	-	0.8	V
		I_O = 12 mA; V_{CC} = 2.7 V	-	-	0.4	-	0.6	V
		I_O = 24 mA; V_{CC} = 3.0 V	-	-	0.55	-	0.8	V
I_I	input leakage current	V_{CC} = 3.6 V; V_I = 5.5 V or GND	-	±0.1	±5	-	±20	μA

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Table 6.   Static characteristics *...continued*
At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	−40 °C to +85 °C			−40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
I_{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL}; $V_{CC} = 3.6$ V; $V_O = 5.5$ V or GND;	-	0.1	±5	-	±20	µA
I_{OFF}	power-off leakage current	$V_{CC} = 0$ V; V_I or $V_O = 5.5$ V	-	0.1	±10	-	±20	µA
I_{CC}	supply current	$V_{CC} = 3.6$ V; $V_I = V_{CC}$ or GND; $I_O = 0$ A	-	0.1	10	-	40	µA
ΔI_{CC}	additional supply current	per input pin; $V_{CC} = 2.7$ V to 3.6 V; $V_I = V_{CC} - 0.6$ V; $I_O = 0$ A	-	5	500	-	5000	µA
C_I	input capacitance	$V_{CC} = 0$ V to 3.6 V; $V_I = $ GND to V_{CC}	-	5.0	-	-	-	pF

[1]   All typical values are measured at $V_{CC} = 3.3$ V (unless stated otherwise) and $T_{amb} = 25$ °C.

10. Dynamic characteristics

Table 7.   Dynamic characteristics
Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		−40 °C to +85 °C			−40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	Dn to Qn; see Figure 7	[2]						
		$V_{CC} = 1.2$ V		-	16.0	-	-	-	ns
		$V_{CC} = 1.65$ V to 1.95 V		2.1	7.8	16.3	2.1	18.8	ns
		$V_{CC} = 2.3$ V to 2.7 V		1.5	4.1	8.0	1.5	9.2	ns
		$V_{CC} = 2.7$ V		1.5	4.1	7.2	1.5	9.0	ns
		$V_{CC} = 3.0$ V to 3.6 V		1.5	3.4	6.2	1.5	8.0	ns
		LE to Qn; see Figure 8	[2]						
		$V_{CC} = 1.2$ V		-	16.0	-	-	-	ns
		$V_{CC} = 1.65$ V to 1.95 V		2.0	7.7	16.0	2.0	18.4	ns
		$V_{CC} = 2.3$ V to 2.7 V		1.5	4.1	7.8	1.5	9.1	ns
		$V_{CC} = 2.7$ V		1.5	3.7	7.5	1.5	9.5	ns
		$V_{CC} = 3.0$ V to 3.6 V		1.5	3.4	6.5	1.5	8.5	ns
t_{en}	enable time	$\overline{OE}$ to Qn; see Figure 9	[2]						
		$V_{CC} = 1.2$ V		-	18.0	-	-	-	ns
		$V_{CC} = 1.65$ V to 1.95 V		1.7	7.5	17.5	1.7	20.2	ns
		$V_{CC} = 2.3$ V to 2.7 V		1.5	4.2	9.2	1.5	10.6	ns
		$V_{CC} = 2.7$ V		1.5	4.2	8.5	1.5	11.0	ns
		$V_{CC} = 3.0$ V to 3.6 V		1.5	3.4	7.5	1.5	9.5	ns

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Table 7. **Dynamic characteristics** *…continued*
Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 11.

Symbol	Parameter	Conditions		–40 °C to +85 °C			–40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
t_{dis}	disable time	$\overline{OE}$ to Qn; see Figure 9	[2]						
		V_{CC} = 1.2 V		-	8.0	-	-	-	ns
		V_{CC} = 1.65 V to 1.95 V		1.0	3.3	10.1	1.0	11.6	ns
		V_{CC} = 2.3 V to 2.7 V		0.3	1.8	5.7	0.3	6.6	ns
		V_{CC} = 2.7 V		1.5	3.0	6.5	1.5	8.5	ns
		V_{CC} = 3.0 V to 3.6 V		1.5	2.5	6.0	1.5	7.5	ns
t_W	pulse width	LE HIGH; see Figure 8							
		V_{CC} = 1.65 V to 1.95 V		5.0	-	-	5.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		4.0	-	-	4.0	-	ns
		V_{CC} = 2.7 V		3.2	-	-	3.2	-	ns
		V_{CC} = 3.0 V to 3.6 V		3.2	1.6	-	3.2	-	ns
t_{su}	set-up time	nD to nCP; see Figure 10							
		V_{CC} = 1.65 V to 1.95 V		4.0	-	-	4.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		2.5	-	-	2.5	-	ns
		V_{CC} = 2.7 V		1.7	-	-	1.7	-	ns
		V_{CC} = 3.0 V to 3.6 V		1.7	-	-	1.7	-	ns
t_h	hold time	Dn to LE; see Figure 10							
		V_{CC} = 1.65 V to 1.95 V		3.0	-	-	3.0	-	ns
		V_{CC} = 2.3 V to 2.7 V		1.9	-	-	1.9	-	ns
		V_{CC} = 2.7 V		1.5	-	-	1.5	-	ns
		V_{CC} = 3.0 V to 3.6 V		1.4	-	-	1.4	-	ns
$t_{sk(o)}$	output skew time	V_{CC} = 3.0 V to 3.6 V	[3]	-	-	1.0	-	1.5	ns
C_{PD}	power dissipation capacitance	per latch; V_I = GND to V_{CC}	[4]						
		V_{CC} = 1.65 V to 1.95 V		-	7.1	-		-	pF
		V_{CC} = 2.3 V to 2.7 V		-	10.3	-		-	pF
		V_{CC} = 3.0 V to 3.6 V		-	13.2	-		-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V and 3.3 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.
t_{en} is the same as t_{PZL} and t_{PZH}.
t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
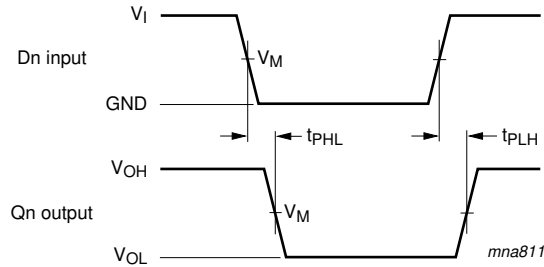f_i = input frequency in MHz; f_o = output frequency in MHz
C_L = output load capacitance in pF
V_{CC} = supply voltage in Volts
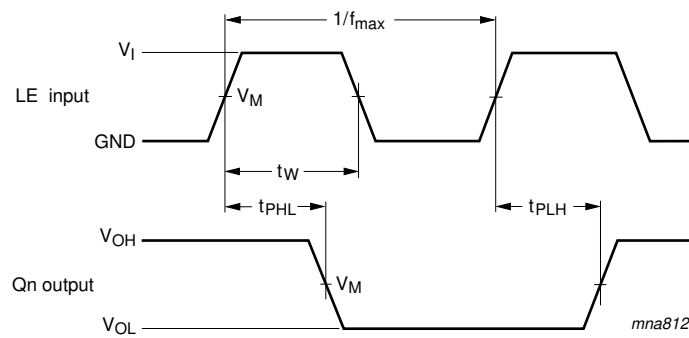N = number of inputs switching
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs

11. AC waveforms

Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 7.   Input (Dn) to output (Qn) propagation delays

Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8.   Latch Enable input (LE) pulse width, the latch enable input to output (Qn) propagation delays
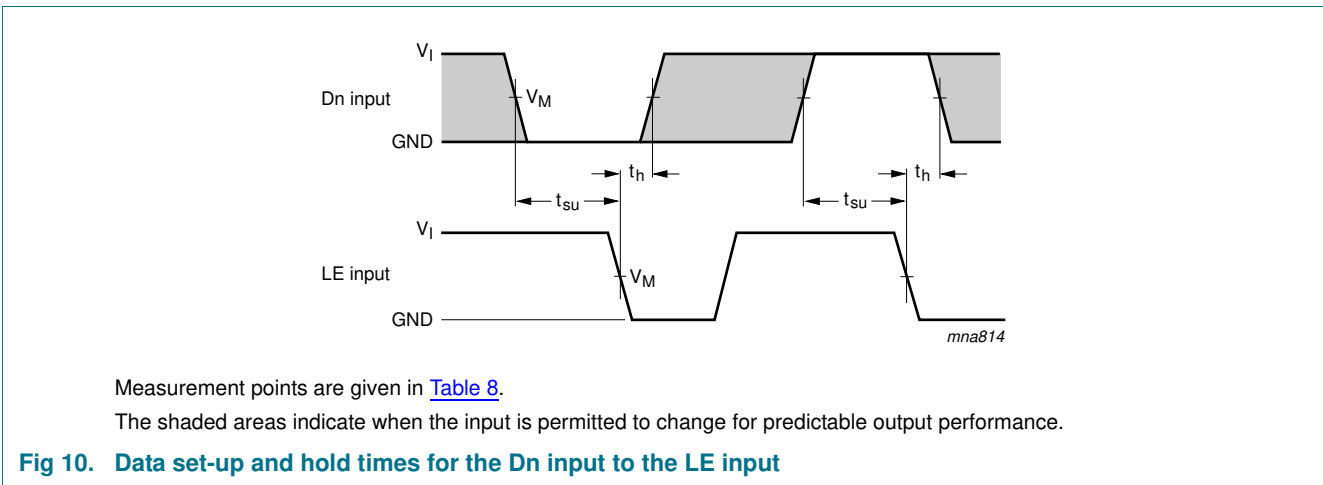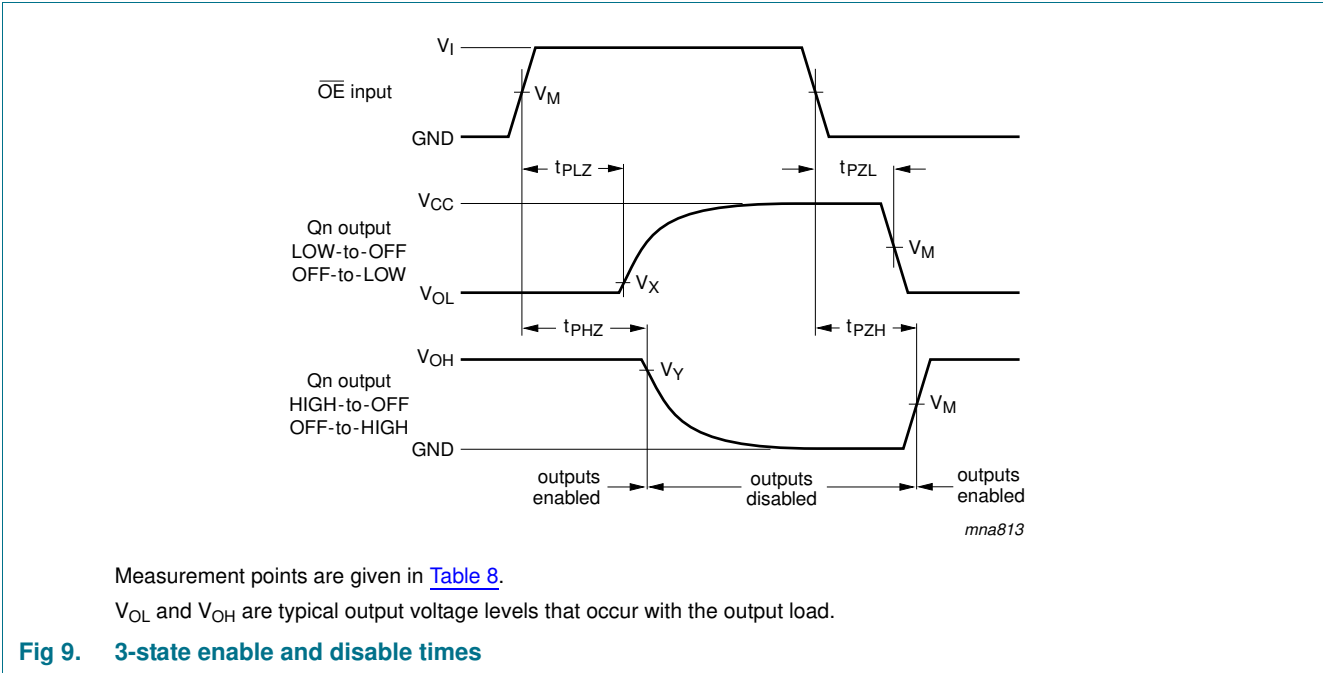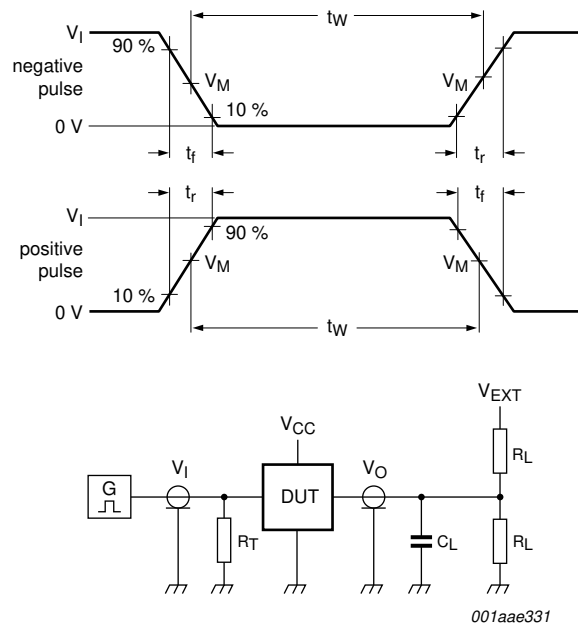
Measurement points are given in Table 8.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 9. **3-state enable and disable times**

Measurement points are given in Table 8.

The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig 10. **Data set-up and hold times for the Dn input to the LE input**

Table 8. **Measurement points**

Supply voltage	Input		Output		
V_{CC}	V_I	V_M	V_M	V_X	V_Y
1.2 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
1.65 V to 1.95 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
2.3 V to 2.7 V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
2.7 V	2.7 V	1.5 V	1.5 V	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V
3.0 V to 3.6 V	2.7 V	1.5 V	1.5 V	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V

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Test data is given in Table 9. Definitions for test circuit:

R_L = Load resistance. C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 11. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V_{EXT}		
	V_I	t_r, t_f	C_L	R_L	t_{PLH}, t_{PHL}	t_{PLZ}, t_{PZL}	t_{PHZ}, t_{PZH}
1.2 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	2 × V_{CC}	GND
1.65 V to 1.95 V	V_{CC}	≤ 2 ns	30 pF	1 kΩ	open	2 × V_{CC}	GND
2.3 V to 2.7 V	V_{CC}	≤ 2 ns	30 pF	500 Ω	open	2 × V_{CC}	GND
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2 × V_{CC}	GND
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	2 × V_{CC}	GND

12. Package outline

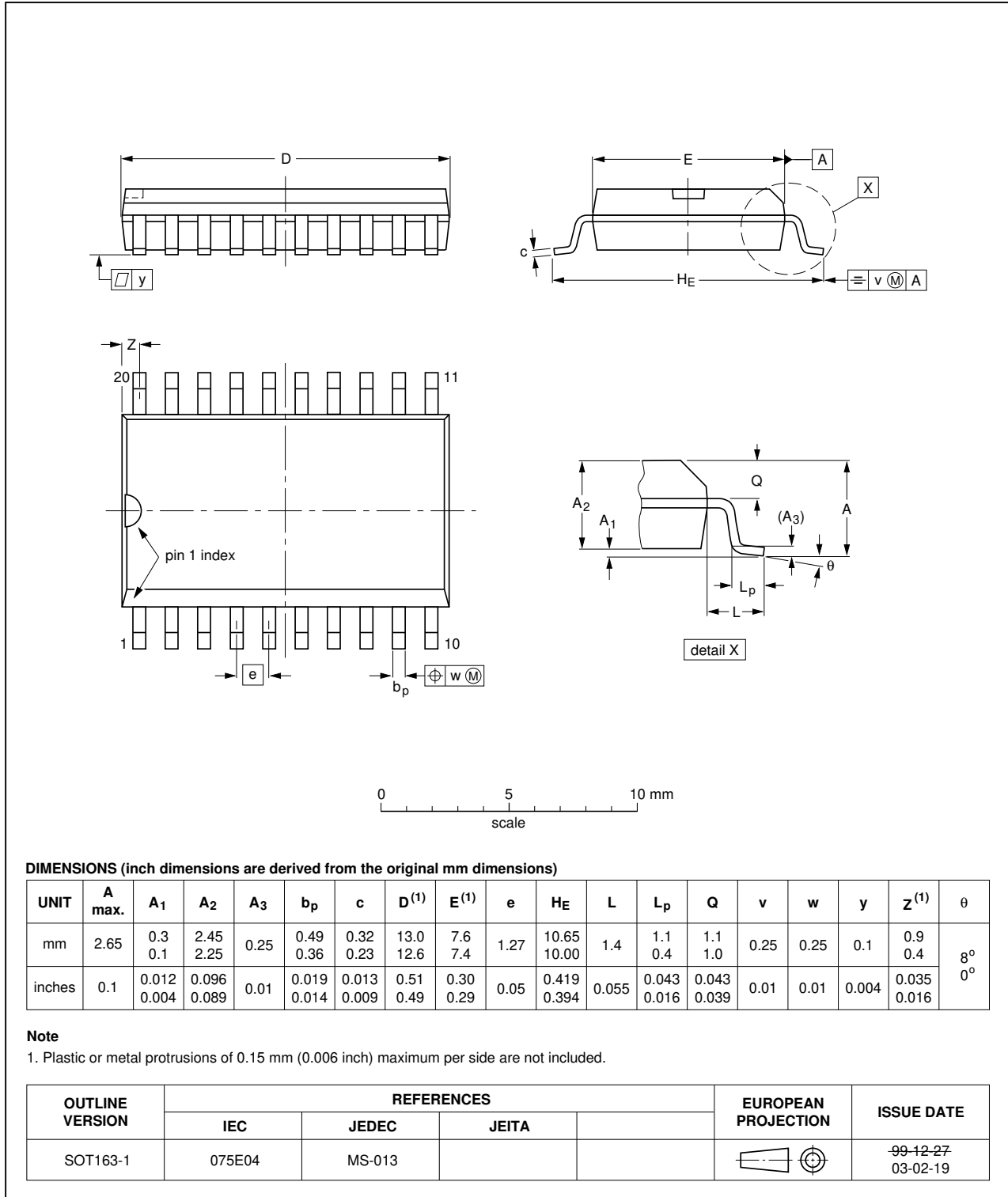**SO20: plastic small outline package; 20 leads; body width 7.5 mm**

SOT163-1

scale

DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	D[1]	E[1]	e	H_E	L	L_p	Q	v	w	y	Z[1]	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8° 0°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT163-1	075E04	MS-013				~~99-12-27~~ 03-02-19

Fig 12. Package outline SOT163-1 (SO20)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm
SOT360-1

DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A₁	A₂	A₃	bₚ	c	D (1)	E (2)	e	HE	L	Lₚ	Q	v	w	y	Z (1)	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT360-1		MO-153				~~99-12-27~~ 03-02-19

Fig 13. Package outline SOT360-1 (TSSOP20)

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm

SOT764-1

DIMENSIONS (mm are the original dimensions)

UNIT	$A^{(1)}$ max.	A_1	b	c	$D^{(1)}$	D_h	$E^{(1)}$	E_h	e	e_1	L	v	w	y	y_1
mm	1	0.05 / 0.00	0.30 / 0.18	0.2	4.6 / 4.4	3.15 / 2.85	2.6 / 2.4	1.15 / 0.85	0.5	3.5	0.5 / 0.3	0.1	0.05	0.05	0.1

Note

1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT764-1	- - -	MO-241	- - -			~~02-10-17~~ 03-01-27
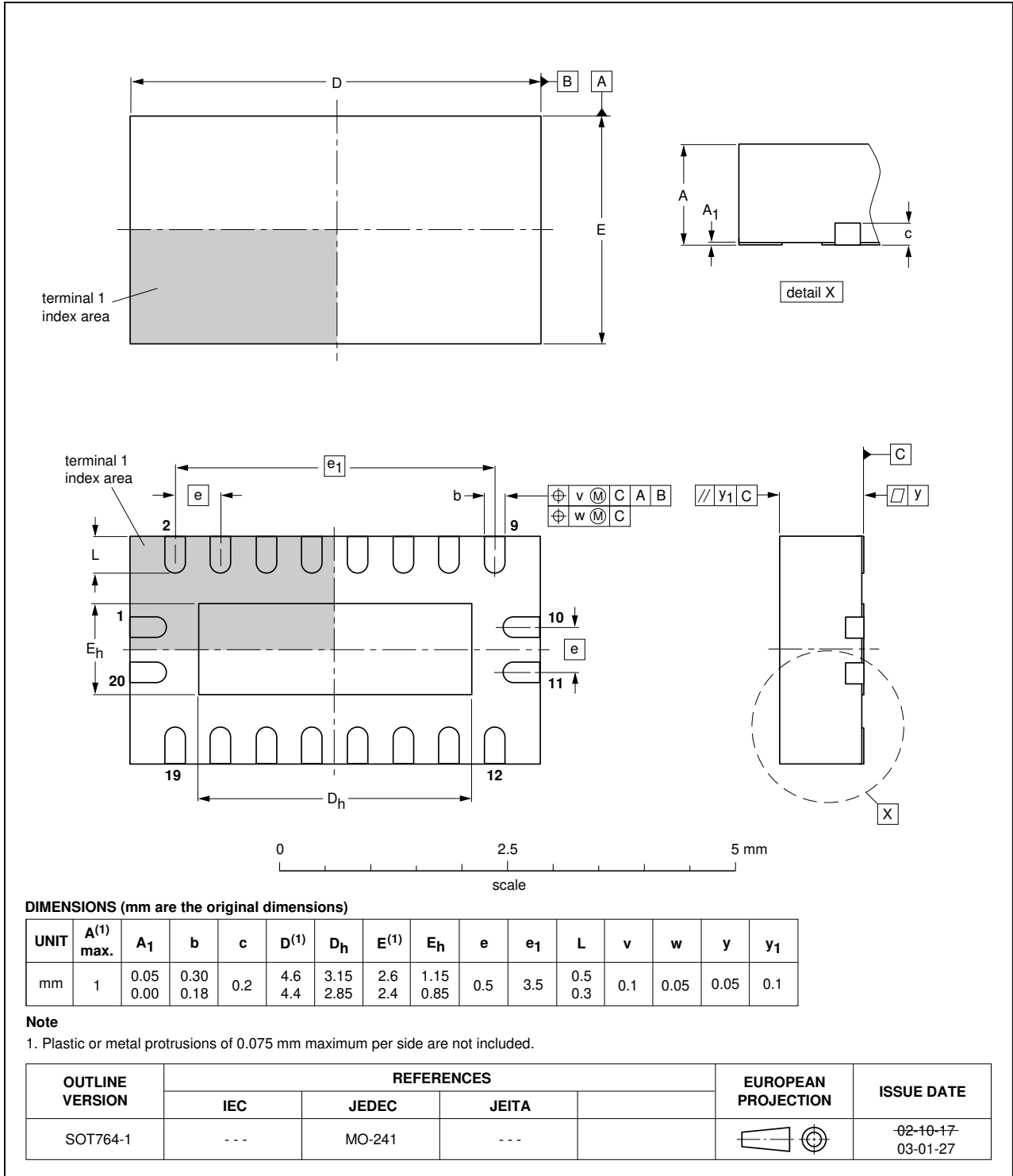
Fig 14. Package outline SOT764-1 (DHVQFN20)

13. Abbreviations

Table 10.   Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11.   Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC573A_Q100 v.1	20130129	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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